PATENT COOPERATION TREATY

PCT

INTERNATIONAL SEARCH REPORT

(PCT Article 18 and Rules 43 and 44)

Applicant's or agent's file reference	FOR FURTHER	coo Form PCT/ICA 1000
WBH.M13	ACTION as v	see Form PCT/ISA/220 vell as, where applicable, item 5 below.
International application No.	International filing date (day/month/year)	(Earliest) Priority Date (day/month/year)
PCT/GB2004/001471	02/04/2004	03/04/2003
Applicant		
		·
MICROEMISSIVE DISPLAYS LIN	MITED	
This International Search Report has been according to Article 18. A copy is being tra	n prepared by this International Searching A ansmitted to the International Bureau.	authority and is transmitted to the applicant
This International Search Report consists	of a total of sheets.	
	a copy of each prior art document cited in the	nis report.
1 Pacis of the rement	· · · · · · · · · · · · · · · · · · ·	
 Basis of the report a. With regard to the language, the language in which it was filed, unl 	international search was carried out on the tess otherwise indicated under this item.	pasis of the international application in the
The international this Authority (Rul	search was carried out on the basis of a trar e 23.1(b)).	nslation of the international application furnished to
b. With regard to any nucleo	otide and/or amino acid sequence disclose	ed in the international application, see Box No. I.
2. Certain claims were four	nd unsearchable (See Box II).	
3. Unity of invention is lack	king (see Box III).	
4. With regard to the title,	• -	
the text is approved as sul	bmitted by the applicant.	
	ned by this Authority to read as follows:	
ION BEAM METHOD FOR RE	MOVING AN ORGANIC LIGHT EM	ITTING MATERIAL
	, 	
	n. ,	
5. With regard to the abstract,		
X the text is approved as sub	omitted by the applicant.	
the text has been establish may, within one month from	ned, according to Rule 38.2(b), by this Authorn the date of mailing of this international sea	ority as it appears in Box No. IV. The applicant arch report, submit comments to this Authority.
6. With regards to the drawings,		
a. the figure of the drawings to be pu	iblished with the abstract is Figure No. $\underline{1}$	
X as suggested by th	e applicant.	
	Authority, because the applicant failed to su	
	Authority, because this figure better charac	terizes the invention.
b none of the figures is to be	published with the abstract.	

INTERNATIONAL SEARCH REPORT

International Application No PCT/GB2004/001471

A. CLASSIFICATION OF SUBJECT MATTER IPC 7 H01L51/56 H01L51/40 According to International Patent Classification (IPC) or to both national classification and IPC **B. FIELDS SEARCHED** Minimum documentation searched (classification system followed by classification symbols) IPC 7 H01L Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched Electronic data base consulted during the international search (name of data base and, where practical, search terms used) EPO-Internal C. DOCUMENTS CONSIDERED TO BE RELEVANT Citation of document, with indication, where appropriate, of the relevant passages Category ° Relevant to claim No. X WO 98/21755 A (GRAHAM TERESITA ORDONEZ; 1,2,4,9, LIEN SHUI CHIH ALAN (US); IBM (US); 11,12 ANGELOPO) 22 May 1998 (1998-05-22) page 2, paragraph 3 page 20, paragraph 2 page 21 page 31, paragraph 4 - page 32, paragraph page 33, paragraph 2 - page 35; figures 18,19 page 36, paragraph 3 page 37, paragraph 2 - page 38, paragraph 1; claims 88,91,93,98,119-121; figures 22,23 2,3,5-8, 10,12 Further documents are listed in the continuation of box C. Patent family members are listed in annex. Special categories of cited documents: "T" later document published after the international filing date or priority date and not in conflict with the application but "A" document defining the general state of the art which is not cited to understand the principle or theory underlying the considered to be of particular relevance invention "E" earlier document but published on or after the international. *X* document of particular relevance; the claimed invention filing date cannot be considered novel or cannot be considered to "L" document which may throw doubts on priority claim(s) or involve an inventive step when the document is taken alone which is cited to establish the publication date of another "Y" document of particular relevance; the claimed invention citation or other special reason (as specified) cannot be considered to involve an inventive step when the *O* document referring to an oral disclosure, use, exhibition or document is combined with one or more other such docuother means ments, such combination being obvious to a person skilled in the art. *P* document published prior to the international filing date but later than the priority date claimed "&" document member of the same patent family Date of the actual completion of the international search Date of mailing of the international search report 27 July 2004 02/08/2004 Name and mailing address of the ISA Authorized officer European Patent Office, P.B. 5818 Patentlaan 2 NL - 2280 HV Rijswijk Tel. (+31-70) 340-2040, Tx. 31 651 epo ni, Klopfenstein, P Fax: (+31-70) 340-3016

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INTERNATIONAL SEARCH REPORT

International Application No PCT/GB2004/001471

	tion) DOCUMENTS CONSIDERED TO BE RELEVANT	
Category °	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X	PATENT ABSTRACTS OF JAPAN vol. 1999, no. 08, 30 June 1999 (1999-06-30) -& JP 11 074084 A (TORAY IND INC), 16 March 1999 (1999-03-16) abstract paragraph '0005! - paragraph '0006!	1,2,4,9,
Υ	paragraph '0009! - paragraph '0011!	3,5-8, 10,12
X	US 5 953 585 A (MIYAGUCHI SATOSHI) 14 September 1999 (1999-09-14) column 1, line 5 - line 17	1,4,9,11
	column 1, line 42 - line 54 column 1, line 55 - column 2, line 22 column 2, line 61 - column 3, line 62; figures 1a-1d	·
Y	· · · · · · · · · · · · · · · · · · ·	2,3,5-8, 10,12
Y	PATENT ABSTRACTS OF JAPAN vol. 2000, no. 10, 17 November 2000 (2000-11-17) -& JP 2000 192224 A (ROHM CO LTD), 11 July 2000 (2000-07-11) abstract paragraph '0006! - paragraph '0013!; figures 13a-13d paragraph '0015! - paragraph '0016! paragraph '0029! - paragraph '0031!; figures 1a,6c paragraph '0054! - paragraph '0057!; figures 6a-6c	3
Y	PATENT ABSTRACTS OF JAPAN vol. 1999, no. 11, 30 September 1999 (1999-09-30) -& JP 11 167987 A (NEC CORP), 22 June 1999 (1999-06-22) abstract paragraph '0006! paragraph '0009! - paragraph '0011!; figures 3,4,7	3
4	PATENT ABSTRACTS OF JAPAN vol. 0091, no. 57 (P-369), 2 July 1985 (1985-07-02) -& JP 60 033501 A (KOGYO GIJUTSUIN; others: 0J), 20 February 1985 (1985-02-20) abstract	5,6
	US 4 233 109 A (NISHIZAWA JUNICHI) 11 November 1980 (1980-11-11) column 1, line 11 - line 43 column 3, line 3 - line 42	7,8

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INTERNATIONAL SEARCH REPORT

Information on patent family members

International Application No
PCT/GB2004/001471

			· · · · · ·			-	
	atent document in search report		Publication date		Patent family member(s)		Publication date
WO	9821755	Α	22-05-1998	EP	0953213	A2	03-11-1999
				JP	2000505249	T	25-04-2000
				TW	557386	В	11-10-2003
				WO	9821755		22-05-1998
				US	6331356	B1	18-12-2001
JP	11074084	Α	16-03-1999	NONE			
US	5953585	Α	14-09-1999	JP	9293589	Α	11-11-1997
JP	2000192224	Α	11-07-2000	NONE			
JP	11167987	Α	22-06-1999	JP	2848384	B2	20-01-1999
JP	60033501	Α	20-02-1985	NONE			هزین، ویی بریان هک باک های هک ادامه برای بیان باید باید و این
UŞ	4233109	Α	11-11-1980	JP	1231795		26-09-1984
				JP	52088238		23-07-1977
				JP	59004506	В	30-01-1984
				JP	1121861	C	12-11-1982
				JP	53028377	Α	16-03-1978
			•	JP	57003213	_	20-01-1982
				JP	1121862		12-11-1982
				JP	53028378	• •	16-03-1978
				JP	57003214		20-01-1982
				US	4371412	A	01-02-1983

PATENT COOPERATION TREATY

From the INTERNATIONAL SEARCHING AUTHORITY PCT To: WRITTEN OPINION OF THE see form PCT/ISA/220 INTERNATIONAL SEARCHING AUTHORITY (PCT Rule 43bis.1) Date of mailing (day/month/year) see form PCT/ISA/210 (second sheet) Applicant's or agent's file reference FOR FURTHER ACTION see form PCT/ISA/220 See paragraph 2 below International application No. International filing date (day/month/year) Priority date (day/month/year) PCT/GB2004/001471 02.04.2004 03.04.2003 International Patent Classification (IPC) or both national classification and IPC H01L51/56, H01L51/40 **Applicant** MICROEMISSIVE DISPLAYS LIMITED This opinion contains indications relating to the following items: ☑ Box No. I Basis of the opinion ☑ Box No. II **Priority** Non-establishment of opinion with regard to novelty, inventive step and industrial applicability Box No. III Box No. IV Lack of unity of invention Box No. V Reasoned statement under Rule 43bis.1(a)(i) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement Box No. VI Certain documents cited Box No. VII Certain defects in the international application Box No. VIII Certain observations on the international application **FURTHER ACTION** If a demand for international preliminary examination is made, this opinion will usually be considered to be a written opinion of the International Preliminary Examining Authority ("IPEA"). However, this does not apply where the applicant chooses an Authority other than this one to be the IPEA and the chosen IPEA has notifed the International Bureau under Rule 66.1 bis(b) that written opinions of this International Searching Authority will not be so considered. If this opinion is, as provided above, considered to be a written opinion of the IPEA, the applicant is invited to submit to the IPEA a written reply together, where appropriate, with amendments, before the expiration of three months from the date of mailing of Form PCT/ISA/220 or before the expiration of 22 months from the priority date, whichever expires later. For further options, see Form PCT/ISA/220. 3. For further details, see notes to Form PCT/ISA/220. Name and mailing address of the ISA: **Authorized Officer**

Klopfenstein, P

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Form PCT/ISA/237 (Cover Sheet) (January 2004)

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European Patent Office - Gitschiner Str. 103

10/55164/

JC20 Recoparition 30 SEP 2009

WRITTEN OPINION OF THE INTERNATIONAL SEARCHING AUTHORITY

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International application No. PCT/GB2004/001471

	Box N	lo. I Basis of the opinion
_	BOX IV	o. i basis of the opinion
1.		egard to the language, this opinion has been established on the basis of the international application in aguage in which it was field, unless otherwise indicated under this item.
	la	nis opinion has been established on the basis of a translation from the original language into the following nguage , which is the language of a translation furnished for the purposes of international search nder Rules 12.3 and 23.1(b)).
2.	With reneces:	egard to any nucleotide and/or amino acid sequence disclosed in the international application and sary to the claimed invention, this opinion has been established on the basis of:
	a. type	e of material:
		a sequence listing
		table(s) related to the sequence listing
	b. form	nat of material:
		in written format
		in computer readable form
	c. time	of filing/furnishing:
		contained in the international application as filed.
	. 🗆	filed together with the international application in computer readable form.
		furnished subsequently to this Authority for the purposes of search.
3.	ha co	addition, in the case that more than one version or copy of a sequence listing and/or table relating thereto is been filed or furnished, the required statements that the information in the subsequent or additional pies is identical to that in the application as filed or does not go beyond the application as filed, as propriate, were furnished.
4.	Additic	nal comments:

WRITTEN OPINION OF THE INTERNATIONAL SEARCHING AUTHORITY

International application No. PCT/GB2004/001471

В	ox No. II	Priority			
. 🗵	The fol	lowing document ha	as not bee	en furnishe	d:
	\boxtimes	copy of the earlier	applicatio	n whose p	riority has been claimed (Rule 43bis.1 and 66.7(a)).
		translation of the ea	arlier app	lication who	ose priority has been claimed (Rule 43bis.1 and 66.7(b)).
	Consec neverth	quently it has not be neless been establis	en possib hed on th	ole to consi ne assumpt	ider the validity of the priority claim. This opinion has ion that the relevant date is the claimed priority date.
	has be	oinion has been esta en found invalid (Ru ate indicated above	ıles 43 <i>bis</i>	.1 and 64.1	rity had been claimed due to the fact that the priority claim 1). Thus for the purposes of this opinion, the international the relevant date.
Λ.	_	bservations, if nece			
. , , ,	dentional c	boor valions, ii nece	33di y .		
R	ov No. V	Passanad stator	mont und	lor Pulo 42	hio 1(o)(i) with regard to povelty, inventive step or
	ox No. V	Reasoned stater	nent und	ler Rule 43	bis.1(a)(i) with regard to novelty, inventive step or no supporting such statement
in	dustrial a	Reasoned stater	nent und	ler Rule 43 explanatio	bis.1(a)(i) with regard to novelty, inventive step or no supporting such statement
in		Reasoned stater	nent und	ler Rule 43 explanatio	bis.1(a)(i) with regard to novelty, inventive step or ns supporting such statement
in . St	dustrial a	Reasoned stater applicability; citation	ons and e	explanatio	ns supporting such statement
in . St	dustrial a	Reasoned stater applicability; citation	Yes:	explanatio Claims	ns supporting such statement 3 5-8 10
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see separate sheet

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JC20 Rec'd PCT/PTO 3 0 SEP 2005

WRITTEN OPINION OF THE INTERNATIONAL SEARCHING AUTHORITY (SEPARATE SHEET)

International application No.

PCT/GB2004/001471

Re Item I

Basis of the opinion

The examination is being carried out on following application documents:

Description:

Pages 1-5 as originally filed

Claims

Claims 1-12 as originally filed

Figures Drawings

Sheet 1/1 as originally filed

Re Item V

Reasoned statement under Rule 66.2(a)(ii) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement

Reference is made to the following documents:

D1: WO-A-98/21755

D2: PATENT ABSTRACTS OF JAPAN & JP-A-11074084

D3: US-A-5953585

D4: PATENT ABSTRACTS OF JAPAN & JP-A-2000192224

D5: PATENT ABSTRACTS OF JAPAN & JP-A-11167987

D6: PATENT ABSTRACTS OF JAPAN & JP-A-60033501

D7: US-A-4233109

V.1 Lack of novelty

The present application does not meet the requirements of the PCT because the subject-matter of claims 1, 2, 4, 9, 11, 12 is not new in the sense of Article 33(2) PCT.

V.1.1 The document **D1** is regarded as being the closest prior art to the subject-matter of **claim 1** and shows (cf. page 2, paragraph 3; page 20, paragraph 2; page 21; page 31, paragraph 4; page 37, paragraph 2 and Fig.22) the fabrication of an organic light emitting device (OLED or diodes), comprising a method of removing an organic light emitting material (ie an electrically conducting polymer, see from page 34, third para- graph to page 35, second paragraph) from defined areas of a substrate (ie from

organic light emitting diode pixels), comprising the steps of arranging a shadow mask (see the metal mask in Fig.22.2) to overlie the organic material other than in the defined areas, and applying a beam of ions to the defined areas through the mask openings, thereby anticipating a method according to **claims 1, 2, 9, 11, 12**. In D1, the ions are chemically reactive with the substrate, see last paragraph of page 37 (features of **claim 4**).

Thus, document D1 anticipates a method according to claims 1, 2, 4, 9, 11, 12.

V.1.2 Also **D2** (cf. abstract, Fig.1, formulae 1-4 and items [9]-[11] and [26], [27]) discloses a method anticipating the features of **claims 1, 2, 4, 9, 11** (see light emitting layer (3) and shadow mask (5)) and **D3** shows in col.1, 42-54; col.2, line 61 to col.3, line 62 and Figs.1A-D a method according to **claims 1, 4, 9, 11**, see light emitting layer (3) and shadow mask (5) (when assessing the relevance of D3, a "shadow mask" was defined as any masking material able to shadow/protect the substrate from the etching ions).

V.2 Lack of inventive step

Dependent claims 3, 5-8, 10 do not contain any features which, in combination with the features of any claim to which they refer, meet the requirements of the PCT in respect of inventive step in the sense of Article 33(3) PCT.

rence of damages to the light-emitting material, in case of a direct contact with the shadow mask (see also description page 2, lines 1-4).

Once having identified the problem, the solution of avoiding or minimizing any direct contact between the shadow mask and the light-emitting layer becomes obvious. Such a contact is minimized either by disposing the mask over the device to be etched (no contact at all) or using a mask with as small as possible contact portions. Moreover, this problem and the two alternative solutions of claim 3 are well known in the art, see D4 (see Figs. 1A and 6C) showing the use of a shadow mask (2) with recesses (2b) located at the portions of the light emitting material (R) defining the pixels (like in the application in page 3, lines 16-20) and document D5 (see Figs. 1c, 3) where a substrate (1) has recesses (5) formed in order to avoid contact between the shadow mask (8) and the light emitting layer (7) at the anode portions (active

portions). In both documents, a contact between mask and light emitting layer is

explicitly to be avoided or minimized for the purpose of protecting the light emitting

layer (using such a shadow mask as a deposition or as an etching mask is irrelevant

V.2.1 The problem to be solved by the features of claim 3 may be regarded as the occu-

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in view of the above problem).

As the features of claim 3 are described in documents **D4** and **D5** as providing the same advantages as in the present application, it would be obvious to the person skilled in the art, namely when the same result is to be achieved, to apply these features with corresponding effect to the etching steps described in any of documents **D1** to **D3** in order to solve the problem posed.

V.2.2 Organic light emitting material can also be usually removed by ion beam etching using inert gas ions, such as Argon, see **D6**, so that the features of **claims 5**, 6 merely represent a customary alternative to the use of chemically reactive ions of D1, coming within the scope of the customary practice followed by persons skilled in the art.

As the document **D1** does not detail the processing parameters of the ion beam etching (IBE) step, the skilled person will look in the art of IBE, which parameters have an influence on the efficiency and precision of IBE and will find from **D7** (cf. col.1, lines 10 to 44 and col.4, lines 3-42) that, as a general principle in any etching method using ion bombardment (ion etching or plasma etching), in order to improve the etching precision, it is preferred to process at high vacuum (pressures of 10⁻⁴ Torr or even higher vacuum, see col.4, lines 15-23) which leads to an increase of the mean free path of the ions and a reduction of collisions between particles, thus improving the directionality and accuracy of the etching of the light emitting polymer layer of D1.

Thus, the features of claims 7, 8 are usual in ion etching and would be selected by the skilled person in D1 aiming to carry out highly minute patterning.

The etched organic material in D1 is formed of an organic layer of an array of organic light emitting diodes, said ion beam removal step could obviously be applied to any exposed portion of said layer, such as for example from bond pad regions, according to **claim 10.** More specifically, these bond pads are located in the application between the pixels (see Fig.1), which is also the location at which the light emitting material is removed in documents D1, D2 and D3.

V.2.3 The reasoning and comments of items V.2.1 and V.2.2 reasoning also apply, mutatis mutandis, to the subject-matter of the corresponding dependent claims, in the light of prior art **D2** and **D3** which therefore are also considered as not involving an inventive step.